

2STA2120

High power PNP epitaxial planar bipolar transistor

Features

- High breakdown voltage V_{CEO} = -250 V
- Complementary to 2STC5948
- Typical f_t = 25 MHz
- Fully characterized at 125 °C

Application

Audio power amplifier

Description

The device is a PNP transistor manufactured using new BiT-LA (Bipolar transistor for linear amplifier) technology. The resulting transistor shows good gain linearity behaviour.

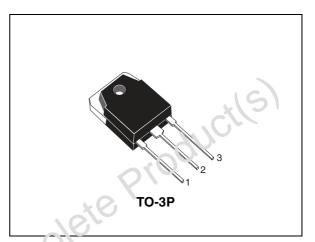
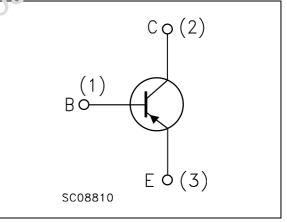


Figure 1. Internal schematic diagram



Order code	Marking	Package	Packaging
2STA2120	2STA2120	TO-3P	Tube

Electrical ratings 1

Tab	ble	2.	
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Absolute maximum rating

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	-250	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	-250	V
V _{EBO}	Emitter-base voltage (I _C = 0)	-6	V
۱ _C	Collector current	-17	Α
I _{CM}	Collector peak current (t _P < 5 ms)	-34	.1
P _{TOT}	Total dissipation at $T_c = 25 \ ^{\circ}C$	200	W
T _{stg}	Storage temperature	· 65 to 150	°C
ТJ	Max. operating junction temperature	150	°C
Table 3.	Thermal data		

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal resistance junction-case max	0.625	°C/W
obsolete P	roducils		

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2 Electrical characteristics

(T_{case} = 25 °C; unless otherwise specified)

Table 4.	Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CBO}	Collector cut-off current $(I_E = 0)$	V _{CB} = -250 V			-5	μA
I _{EBO}	Emitter cut-off current (I _C = 0)	V _{EB} = -6 V			-5	μA
V _{(BR)CEO} ⁽¹⁾	Collector-emitter breakdown voltage (I _B = 0)	I _C = -50 mA	-250			
V _{(BR)CBO}	Collector-base breakdown voltage (I _E = 0)	I _C = -100 μA	-250			V
V _{(BR)EBO} ⁽¹⁾	Emitter-base breakdown voltage (I _C = 0)	I _E = -1 mA	-6			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	I _C = -8 A (5 = -300 mA			-3	V
$V_{BE}^{(1)}$	Base-emitter voltage	$I_{C} = -7$ A $V_{CE} = -5$ V			-1.5	۷
h _{FE}	DC current gain	$I_{C} = .1 A$ $V_{CE} = .5 V$ $i_{C} = .7 A$ $V_{CE} = .5 V$	80 35		160	
f _T	Transition frequency	$I_{C} = -1 A$ $V_{CE} = -5 V$		25		MHz

1. Pulsed duration = 300 µs, duty cycle ≤1.5%



2.1 Electrical characteristics (curves)

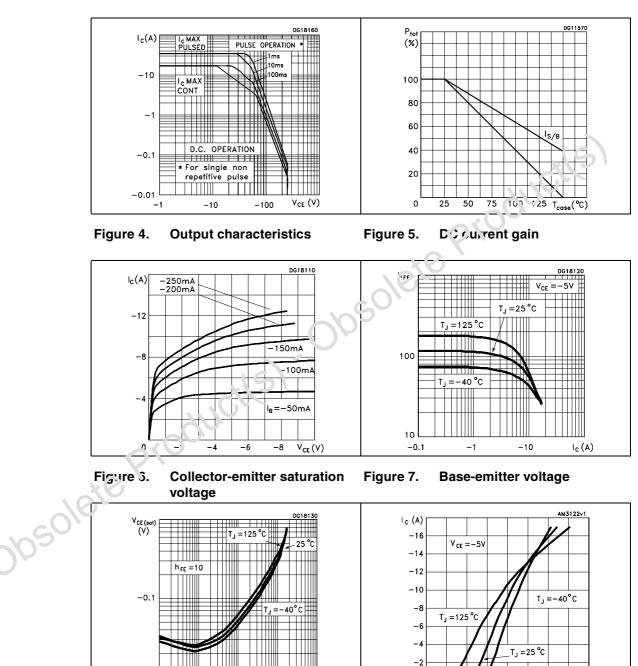


Figure 2. Safe operating area

Figure 3. Derating curve

0 -0.2 -0.4 -0.6 -0.8 -1.0 -1.2 -1.4 V_{BE} (V)

_0.01 ∟ _0.01

-1

-10

I_c (A)

-0.1

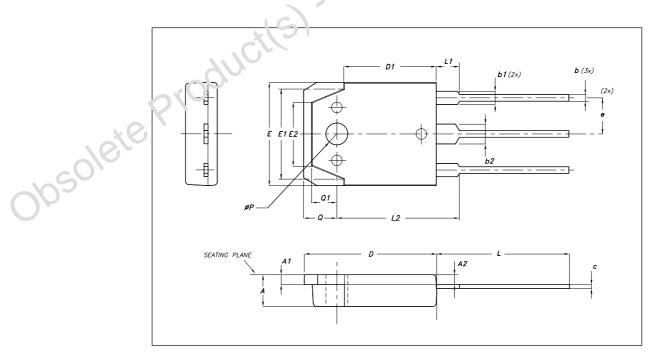
3 Package mechanical data

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a Lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: www.st.com

obsolete Product(s). Obsolete Product(s)

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TO-3P Mechanical data					
DIM.		mm.			
	MIN.	ТҮР	MAX.		
A	4.6		5		
A1	1.45	1.50	1.65		
A2	1.20	1.40	1.60		
b	0.80	1	1.20		
b1	1.80		2.20		
b2	2.80		3.20		
с	0.55	0.60	(.75		
D	19.70	19.90	20.10		
D1		13.90			
E	15.40		15.80		
E1		13.60			
E2		9.60			
e	5.15	5.45	5.75		
L	19.50	20	20.50		
L1		00			
L2	18.20	13.40	18.60		
P	3.10	5	3.30		
Q		5			
Q1		3.80			



4 Revision history

Table 5.Document revision history

	Date	Revision	Changes
	23-Nov-2007	1	Initial release
	09-May-2008	2	Added new graphics.
	07-Nov-2008	3	Document status promoted from preliminary data to datasheet.
obsole	teprod		Document status promoted from preliminary data to datasheet.



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